



DXT5401

PNP SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary NPN Type Available (DXT5551)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)

Mechanical Data

- Case: SOT89-3L
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.055 grams (approximate)

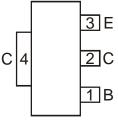


Top View



COLLECTOR

Device Schematic



Pin Out Configuration

Maximum Ratings $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-160	V
Collector-Emitter Voltage	V _{CEO}	-150	V
Emitter-Base Voltage	V _{EBO}	-5.0	V
Collector Current	Ιc	-600	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation $@T_A = 25^{\circ}C$ (Note 3)	PD	1	W
Thermal Resistance, Junction to Ambient $@T_A = 25^{\circ}C$ (Note 3)	$R_{ heta JA}$	125	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	٥°

Notes: 1. No purposefully added lead.

2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

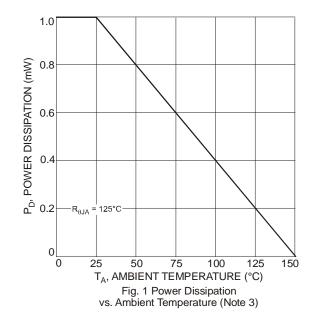
3. Device mounted on FR-4 PCB, pad layout as shown on page 4 or in Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

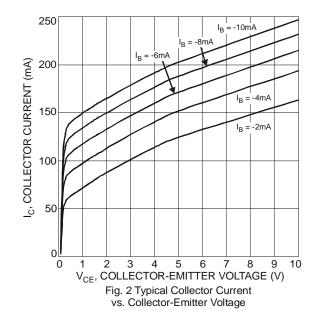


Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 4)					
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-160		V	$I_{C} = -100 \mu A, I_{E} = 0$
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-150		V	$I_{\rm C} = -1.0 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-5.0	_	V	$I_{E} = -10\mu A, I_{C} = 0$
Collector Cutoff Current	I _{CBO}	—	-50	nA μA	$V_{CB} = -120V, I_E = 0$ $V_{CB} = -120V, I_E = 0, T_A = 100^{\circ}C$
Emitter Cutoff Current	I _{EBO}	_	-50	nA	$V_{EB} = -3.0V, I_{C} = 0$
ON CHARACTERISTICS (Note 4)					
DC Current Gain	h _{FE}	50 60 50	 240 		$V_{CE} = -5.0V, I_C = -1.0mA$ $V_{CE} = -5.0V, I_C = -10mA$ $V_{CE} = -5.0V, I_C = -50mA$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	-0.2 -0.5	V	$I_{C} = -10mA$, $I_{B} = -1.0mA$ $I_{C} = -50mA$, $I_{B} = -5.0mA$
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_	-1.0	V	$I_{C} = -10mA$, $I_{B} = -1.0mA$ $I_{C} = -50mA$, $I_{B} = -5.0mA$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	Cobo	_	6.0	pF	$V_{CB} = -10V$, f = 1.0MHz, I _E = 0
Small Signal Current Gain	h _{fe}	40	200		V _{CE} = -10V, I _C = -1.0mA, f = 1.0kHz
Current Gain-Bandwidth Product	f⊤	100	300	MHz	V _{CE} = -10V, I _C = -10mA, f = 100MHz
Noise Figure	NF	_	8.0	dB	V_{CE} = -5.0V, I _C = -200µA, R _S = 10Ω, f = 1.0kHz

Notes: 4. Measured under pulsed conditions. Pulse width = 300μ s. Duty cycle $\leq 2\%$.

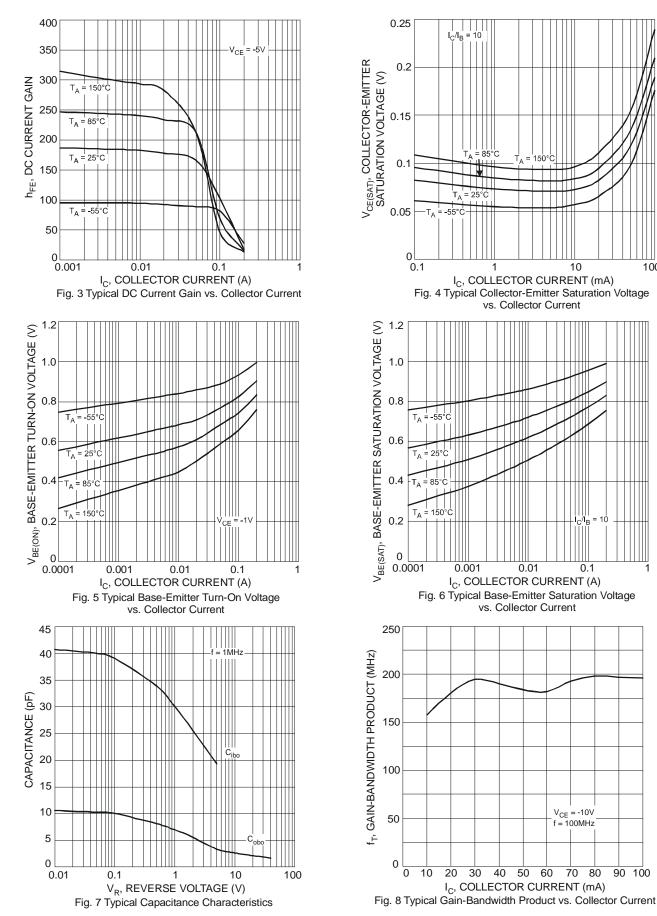








100



90 100



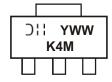
Ordering Information (Note 5)

Part Number	Case	Packaging
DXT5401-13	SOT89-3L	2500/Tape & Reel

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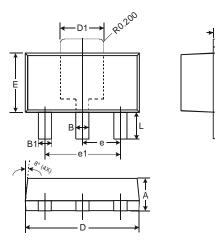
Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



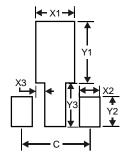
K4M = Product type marking code \bigcirc = Manufacturer's code marking YWW = Date code marking Y = Last digit of year (ex: 7 = 2007) WW = Week code (01 - 53)

Package Outline Dimensions



SOT89-3L				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.43		
D	4.40	4.60		
D1	1.52	1.83		
E	2.29	2.60		
е	1.50 Typ			
e1	3.00 Typ			
Н	3.94	4.25		
L	0.89	1.20		
All Dimensions in mm				

Suggested Pad Layout



Dimensions	Value (in mm)
X1	1.7
X2	0.9
X3	0.4
Y1	2.7
Y2	1.3
Y3	1.9
С	3.0



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